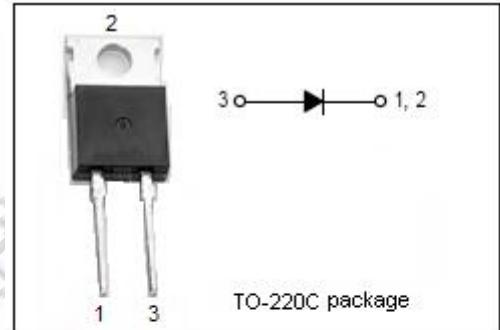


Ultrafast Recovery Rectifier

MUR8100E

FEATURES

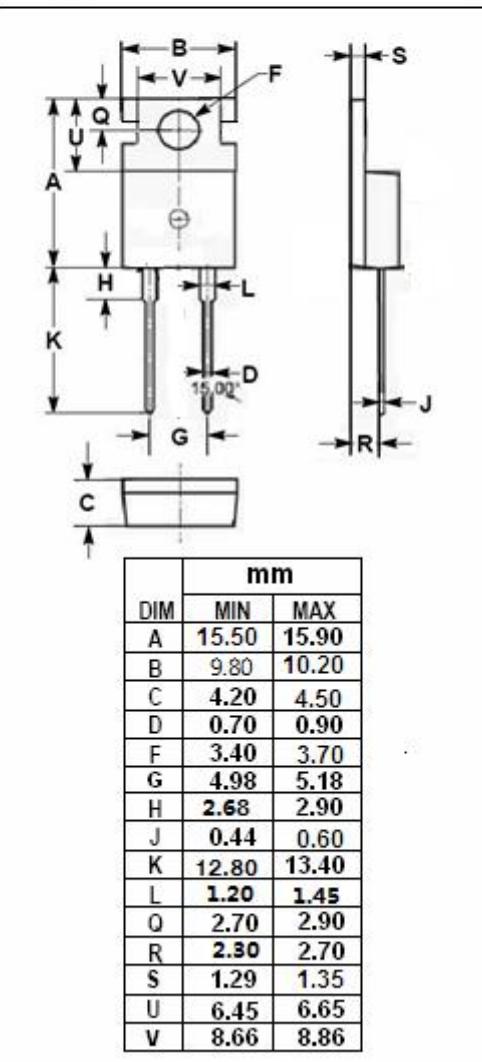
- Ultrafast Recovery Time
- Low Forward Voltage
- Low Leakage Current
- 175°C Operating Junction Temperature
- High Temperature Glass Passivated Junction
- Minimum Lot-to-Lot variations for robust device performance and reliable operation


APPLICATIONS

- Designed for use in switching power supplies and other power Switching applications.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{RMM}	Peak Repetitive Reverse Voltage		
V_{RWM}	Working Peak Reverse Voltage	1000	V
V_R	DC Blocking Voltage		
$I_{F(AV)}$	Average Rectified Forward Current (Rated V_R)	8	A
I_{FM}	Peak Repetitive Forward Current (Rated V_R ,Square Wave,20kHz)	16	A
I_{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	100	A
T_J	Junction Temperature	-55~175	°C
T_{stg}	Storage Temperature Range	-55~175	°C



Ultrafast Recovery Rectifier**MUR8100E****THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance,Junction to Case	2.0	°C/W

ELECTRICAL CHARACTERISTICS($T_a=25^\circ C$) (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_F	Maximum Instantaneous Forward Voltage	$I_F = 8A$	1.8	V
		$I_F = 8A; T_c = 150^\circ C$	1.5	V
I_R	Maximum Instantaneous Reverse Current	$V_{RRM} = 1000V$	100	μ A
		$V_{RRM} = 1000V; T_c = 150^\circ C$	500	μ A
t_{rr}	Maximum Reverse Recovery Time	$I_F = 1A$	85	ns